NSN 5961-01-176-4537

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-176-4537

Inclosure Material:

Plastic

Overall Length:

0.650 inches

Overall Height:

0.190 inches

Overall Width:

0.420 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 1.0 collector to emitter saturation voltage

Current Rating Per Characteristic:

15.00 amperes source cutoff current

Power Rating Per Characteristic:

85.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

35.0 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0